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THIRD SERIES, VOLUME 53, NUMBER 3 *CONTENTS* **15 JANUARY 1996-I**

BRIEF REPORTS

Electronic structure: wide-band, narrow-band, and strongly correlated systems

Influence of gradient corrections on the bulk and surface properties of TiO_2 and SnO_2 957
J. Goniakowski, J. M. Holender, L. N. Kantorovich, M. J. Gillan, and J. A. White

Binding energy of the stabilized uniform interstitial electron gas in transition metals 961
Kazimierz F. Wojciechowski

Electronic states of the θ' phase in Cu-Al alloys as compared to $C16$-$CuAl_2$: Cu $L\alpha$ emission excited directly by undulator radiation 965
C. Dallera, B. De Michelis, E. Puppin, L. Braicovich, and N. B. Brookes

Approach to density-functional ionization energy 969
Mel Levy and Andreas Görling

Depinning transition in Mott-Anderson insulators 973
F. Ladieu, M. Sanquer, and J. P. Bouchaud

Influence of intra-atomic correlation effects on 3*d* states in transition-metal compounds 977
R. Dagys and A. Kancerevičius

Environment-dependent tight-binding potential model 979
M. S. Tang, C. Z. Wang, C. T. Chan, and K. M. Ho

Evidence for ideal insulating or conducting state in a one-dimensional integrable system 983
X. Zotos and P. Prelovšek

Semiconductors I: bulk

LO-phonon and plasmon coupling in neutron-transmutation-doped GaAs 987
K. Kuriyama, K. Sakai, and M. Okada

Semiconductors II: surfaces, interfaces, microstructures, and related topics

Thermodynamic properties of particles with intermediate statistics 990
Geoffrey S. Joyce, Sarben Sarkar, Jozef Spałek, and Krzysztof Byczuk

Resonant-tunneling spectroscopy of coupled hole subbands in strained Si/SiGe triple-barrier structures 994
B. Ferland, C. D. Akyüz, A. Zaslavsky, and T. O. Sedgwick

Monte Carlo simulation of In surface segregation during the growth of $In_xGa_{1-x}As$ on GaAs(001) 998
N. Grandjean, J. Massies, and M. Leroux

Vicinal Si(100) surfaces under external strain 1002
K. Cho, J. D. Joannopoulos, and A. Nihat Berker

Persistent current of one-dimensional perfect rings under the canonical ensemble 1006
Man-Kit Yip, Jiu-Ren Zheng, and Ho-Fai Cheung

Near-infrared photonic band gap of two-dimensional triangular air-rod lattices as revealed by transmittance measurement 1010
K. Inoue, M. Wada, K. Sakoda, M. Hayashi, T. Fukushima, and A. Yamanaka

Crossover behavior of the conductance oscillations in a quasi-one-dimensional ring in the ballistic limit 1014
Mincheol Shin, Kyoung Wan Park, Seongjae Lee, and El-Hang Lee

Absorption spectra of $GaAs/Al_xGa_{1-x}As$ random superlattices at 2 K 1018
G. F. Lorusso, V. Capozzi, J. L. Staehli, C. Flesia, D. Martin, and P. Favia

(Continued)

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